

# **DCR610D34**

# **Phase Control Thyristor**

DS6048-2 June 2019 (LN38868)

## **FEATURES**

- Double Side Cooling
- High Surge Capability

### **APPLICATIONS**

- High Power Drives
- High Voltage Power Supplies
- Static Switches

### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>RRM</sub> V	Conditions
DCR610D34 DCR610D32 DCR610D30 DCR610D28 DCR610D26 DCR610D24	3400 3200 3000 2800 2600 2400	$\begin{split} T_{vj} &= \text{-}40^{\circ}\text{C to 125}^{\circ}\text{C}, \\ I_{DRM} &= I_{RRM} = 50\text{mA}, \\ V_{DRM}, V_{RRM}  t_p &= 10\text{ms}, \\ V_{DSM}  \&  V_{RSM} &= \\ V_{DRM}  \&  V_{RRM}  + 100V \\ respectively \end{split}$

Lower voltage grades available.

## **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR610D34

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

#### **KEY PARAMETERS**

$V_{DRM}$	3400 V
I <sub>T(AV)</sub>	610 A
I <sub>TSM</sub>	8000 A
dV/dt*	1000 V/µs
dl/dt	150 A/μs

### \* Higher dV/dt selections available

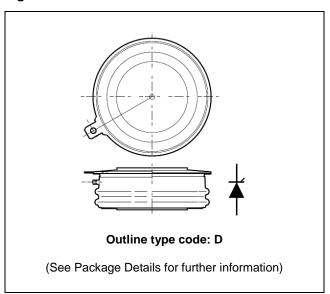


Fig. 1 Package outline



## **CURRENT RATINGS**

## $T_{case} = 60$ °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	Double Side Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	610	А
I <sub>T(RMS)</sub>	RMS value	-	960	А
I <sub>T</sub>	Continuous (direct) on-state current	-	860	А

## **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	8.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	0.32	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.035	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	DC		0.01	°C/W
T <sub>vj</sub>	Virtual junction temperature	Blocking V <sub>DRM</sub> / <sub>VRRM</sub>		-	125	°C
T <sub>stg</sub>	Storage temperature range			-40	140	°C
Fm	Clamping force			8	12	kN



## **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		-	50	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 1000A	Repetitive 50Hz	-	150	A/µs
		Gate source 30V, 10Ω,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125 ^{\circ} C$				
V <sub>T</sub>	On-state voltage	I <sub>T</sub> = 1500A, T <sub>case</sub> = 125°C			2.78	٧
V <sub>T(TO)</sub>	Threshold voltage	T <sub>case</sub> = 125°C		-	0.98	V
r <sub>T</sub>	On-state slope resistance	T <sub>case</sub> = 125°C		-	1.20	mΩ
t <sub>gd</sub>	Delay time	$V_D = 67\% V_{DRM}$ , gate source 30V, $10\Omega$		-	3.0	μs
	·	$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
Ι <sub>L</sub>	Latching current	T <sub>j</sub> = 25°C,		-	1	Α
Ін	Holding current	T <sub>j</sub> = 25°C,		-	200	mA

## **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter Test Conditions		Max.	Units
$V_{GT}$	Gate trigger voltage	V <sub>DRM</sub> = 5V, T <sub>case</sub> = 25°C	3	V
$V_{GD}$	Gate non-trigger voltage	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	0.3	V
I <sub>GT</sub>	Gate trigger current	V <sub>DRM</sub> = 5V, T <sub>case</sub> = 25°C	300	mA
I <sub>GD</sub>	Gate non-trigger current	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	20	mA



## **CURVES**

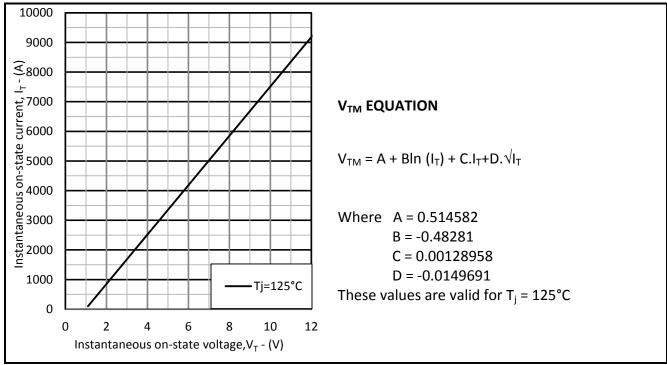


Fig.2 Maximum &minimum on-state characteristics

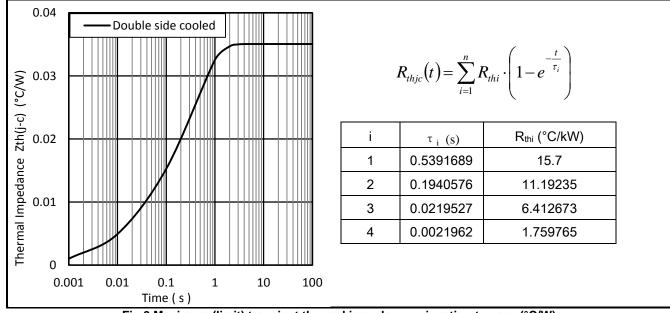
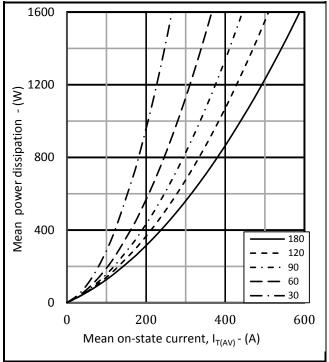
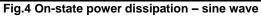


Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)







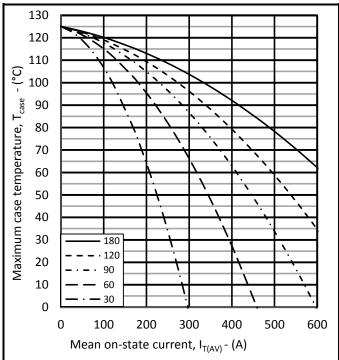


Fig.5 Maximum permissible case temperature, double side cooled – sine wave

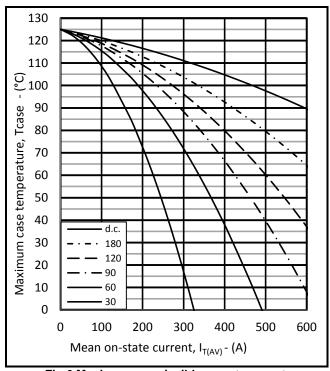


Fig.6 Maximum permissible case temperature, double side cooled – rectangular wave

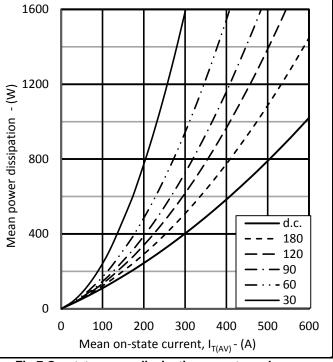
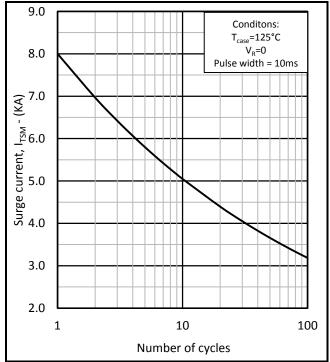
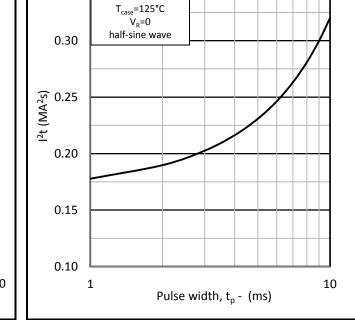


Fig.7 On-state power dissipation - rectangular wave







Conditions:

0.35

Fig.8 Multi-cycle surge current

Fig.9 Single-cycle I<sup>2</sup>t

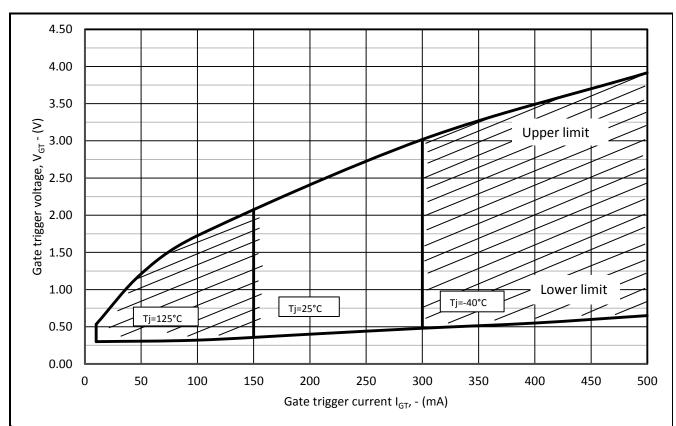


Fig.10 Gate characteristics

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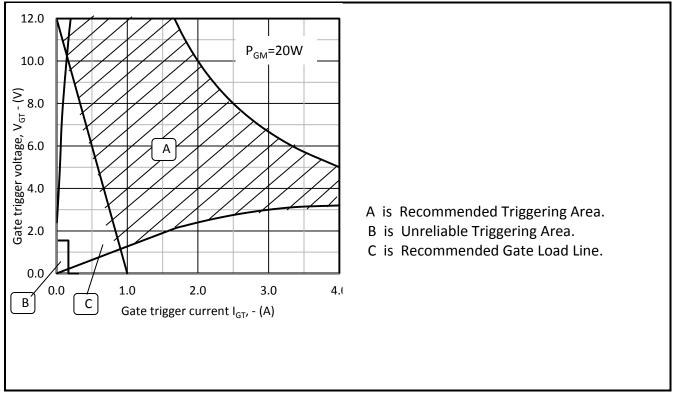


Fig.11 Gate characteristics



## **PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

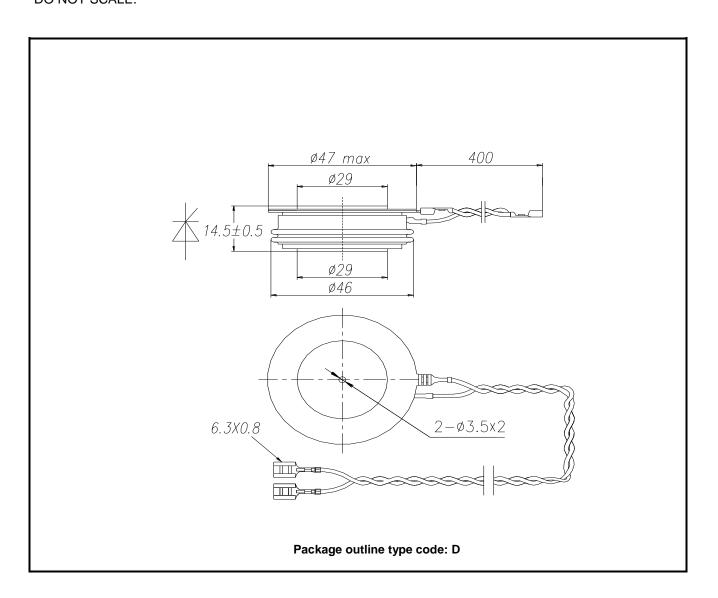


Fig.12 Package outline



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